

Features

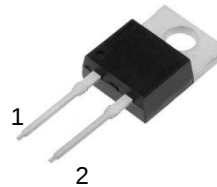
- Low reverse current
- Good surge current capability
- Low capacitive charge
- No reverse recovery current
- Suffix "-Q1" for AEC-Q101

V_{RRM}	=	650	V
$I_F (T_C = 160^{\circ}C)$	=	8	A
Q_C	=	23	nC

Benefits

- System efficiency improvement over Si diodes
- Higher switching frequency
- Increased power density
- Essentially no switching losses

Package



TO-220-2

Applications

- Switch mode power supplies (SMPS)
- Uninterruptible power supplies
- On Board Charger
- UPS



Part Number	Package	Marking
ASZD008065A	TO-220-2	ASZD008065A

Maximum Ratings ($T_C=25^{\circ}\text{C}$ unless otherwise specified)

Symbol	Parameter	Test conditions	Value	Unit
V_{RRM}	Repetitive peak reverse voltage		650	V
V_{RSM}	Non-repetitive peak reverse voltage		650	V
I_F	Continuous forward current	$T_C=25^{\circ}\text{C}$ $T_C=135^{\circ}\text{C}$ $T_C=160^{\circ}\text{C}$	30 15 8	A
I_{FRM}	Repetitive forward surge current	$T_C=25^{\circ}\text{C}$, $t_p=10\text{ms}$, Half Sine Pulse $T_C=110^{\circ}\text{C}$, $t_p=10\text{ms}$, Half Sine Pulse	38 25	A
I_{FSM}	Non-Repetitive forward surge current	$T_C=25^{\circ}\text{C}$, $t_p=10\text{ms}$, Half Sine Pulse $T_C=110^{\circ}\text{C}$, $t_p=10\text{ms}$, Half Sine Pulse	64 53	A
$\int i^2 dt$	i^2t value	$T_C=25^{\circ}\text{C}$, $t_p=10\text{ms}$, Half Sine Pulse $T_C=110^{\circ}\text{C}$, $t_p=10\text{ms}$, Half Sine Pulse	20.5 14	A^2S
P_{tot}	Power dissipation	$T_C=25^{\circ}\text{C}$ $T_C=110^{\circ}\text{C}$	93 40	W
T_j	Operating junction temperature		-55~175	$^{\circ}\text{C}$
T_{stg}	Storage temperature		-55~150	$^{\circ}\text{C}$

Electrical Characteristics ($T_j=25^{\circ}\text{C}$ unless otherwise specified)
Static Characteristics

Symbol	Parameter	Test conditions	Value			Unit
			Min.	Typ.	Max.	
V_{DC}	DC blocking voltage	$T_j=25^{\circ}\text{C}$	650			V
V_F	Diode forward voltage	$I_F=8\text{A}$ $T_j=25^{\circ}\text{C}$ $I_F=8\text{A}$ $T_j=175^{\circ}\text{C}$		1.3 1.5	1.5	V
I_R	Reverse current	$V_R=650\text{V}$ $T_j=25^{\circ}\text{C}$ $V_R=650\text{V}$ $T_j=175^{\circ}\text{C}$			50 200	μA

AC Characteristics ($T_j=25^{\circ}\text{C}$ unless otherwise specified)

Symbol	Parameter	Test conditions	Value			Unit
			Min.	Typ.	Max.	
Q_C	Total capacitive charge	$V_R=400\text{V}$ $T_j=25^{\circ}\text{C}$ $Q_C = \int_0^{V_R} C(V) dV$		23		nC
C	Total capacitance	$V_R=0\text{V}$ $f=1\text{MHz}$ $V_R=200\text{V}$ $f=1\text{MHz}$ $V_R=400\text{V}$ $f=1\text{MHz}$		466 47 38		pF

Thermal Characteristics

Symbol	Parameter	Value			Unit
		Min.	Typ.	Max.	
$R_{th(jc)}$	Thermal resistance from junction to case		1.60		$^{\circ}\text{C/W}$

Typical Performance

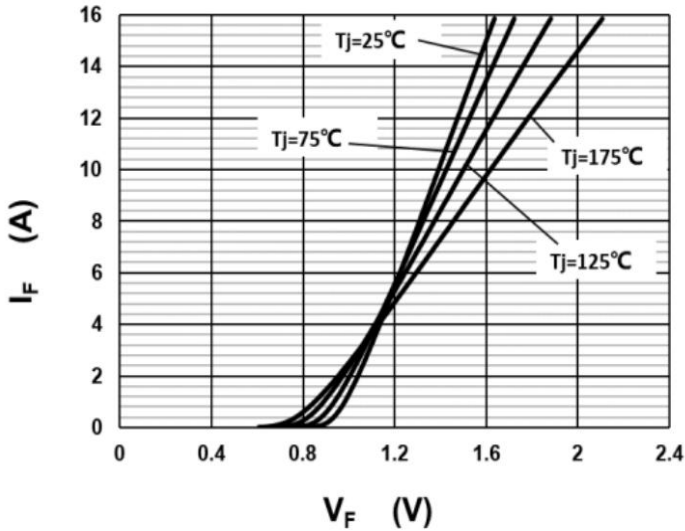


Figure 1. Typical forward characteristics

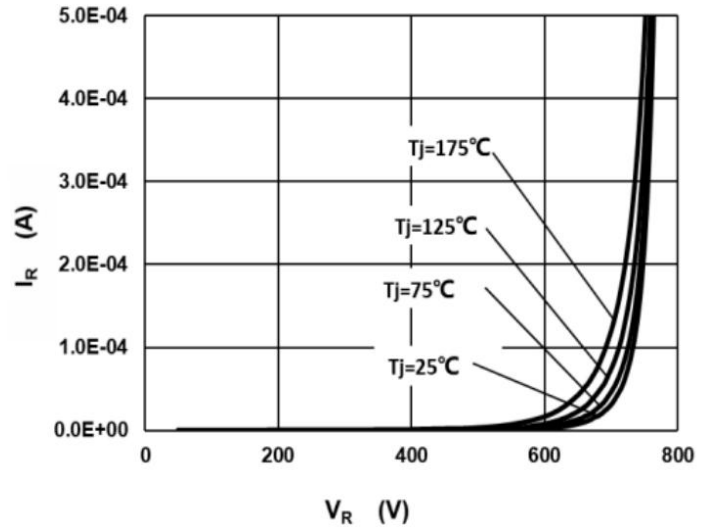


Figure 2. Typical reverse current as function of reverse voltage

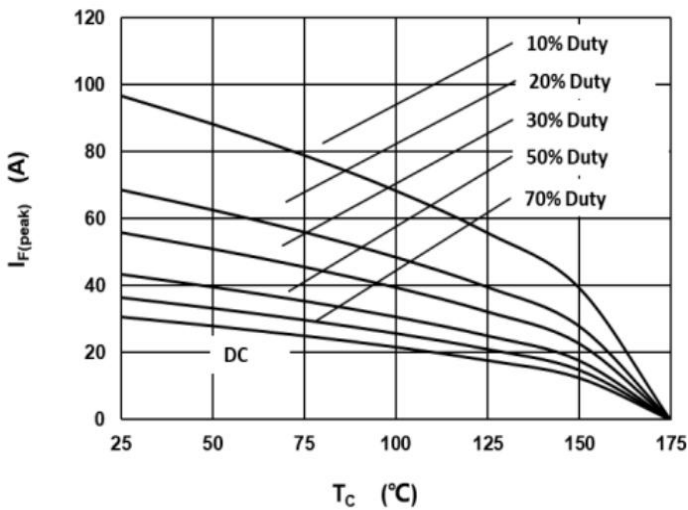


Figure 3. Diode forward current as function of temperature, D=duty cycle

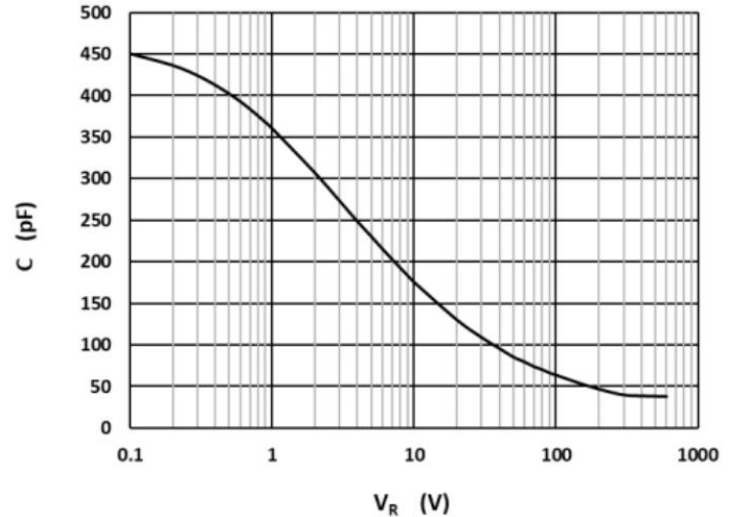


Figure 4. Typical capacitance as function of reverse voltage, $C=f(V_R)$; $T_J=25^\circ\text{C}$

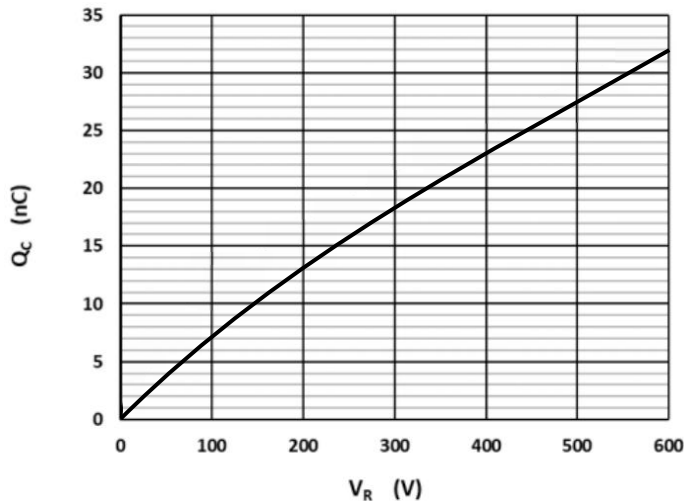


Figure 5. Typical reverse charge as function of reverse voltage

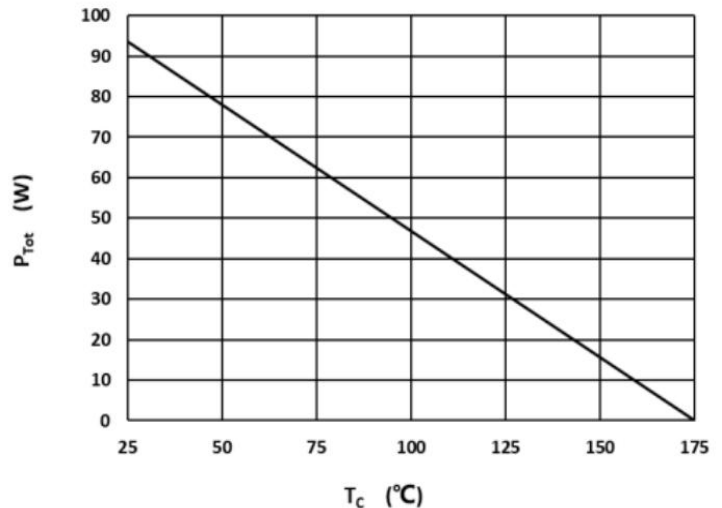


Figure 6. Power dissipation as function of case temperature

Typical Performance

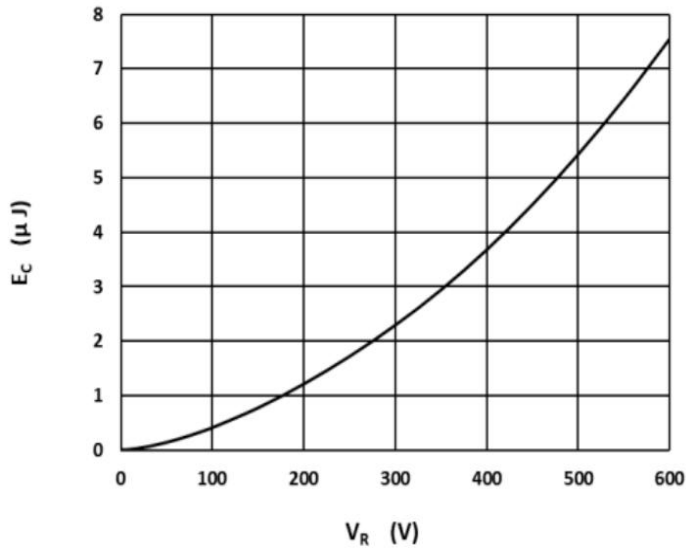


Figure 7. Capacitance stored energy

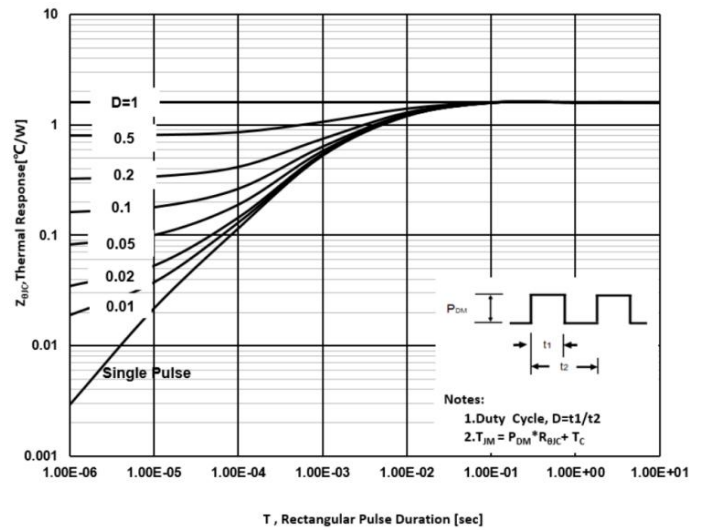
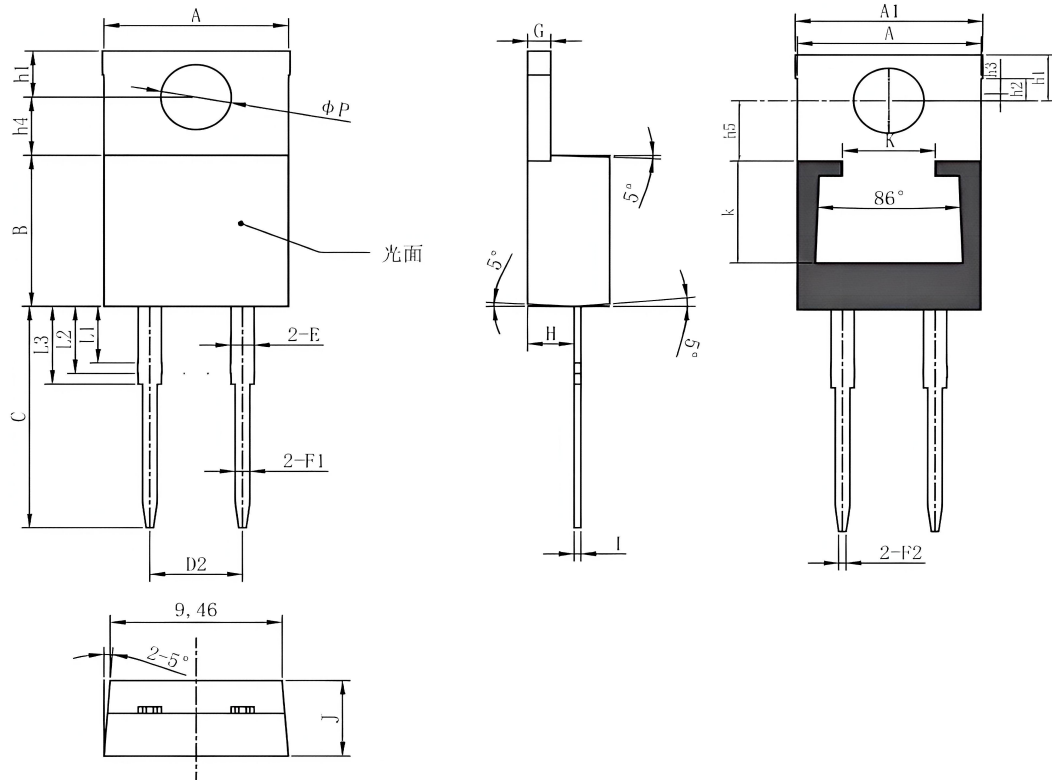


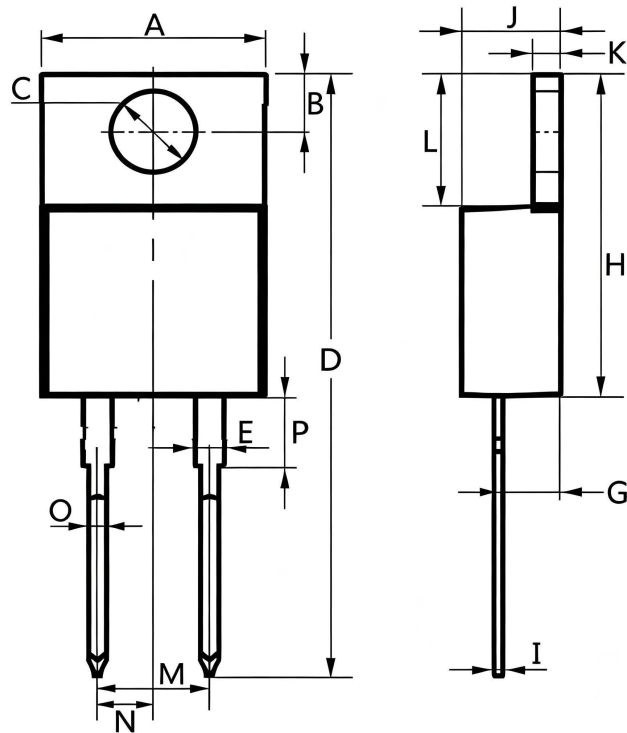
Figure 8. Max. transient thermal impedance

TO-220-2 Package Dimensions (View 1)



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	10.000	10.200	0.394	0.402
A1	10.100	10.500	0.398	0.413
A2	9.800	10.00	0.386	0.394
B	8.800	9.200	0.346	0.362
C	12.800	13.400	0.504	0.528
D2	5.080 Typ		0.200 Typ	
E	1.270	1.400	0.050	0.055
F1	0.750	0.850	0.030	0.033
G	1.260	1.280	0.050	0.050
H	2.400	2.700	0.094	0.106
h1	2.700	2.800	0.106	0.110
h2	1.270	1.370	0.050	0.054
h3	0.400	0.450	0.016	0.018
h4	3.400	3.500	0.134	0.138
h5	3.600	3.650	0.142	0.144
I	0.350	0.450	0.014	0.018
J	4.450	4.600	0.175	0.181
K	4.900	5.100	0.193	0.201
k	6.000	6.050	0.236	0.238
L1	3.300	3.500	0.130	0.138
L2	3.900	4.100	0.154	0.161
L3	4.500	4.700	0.177	0.185
φ P	3.750	3.900	0.148	0.154

TO-220-2 Package Dimensions (View 2)



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	10.150	10.350	0.400	0.407
B	2.650	2.950	0.104	0.116
C	3.700	3.900	0.146	0.154
D	28.500	29.500	1.122	1.161
E	1.300	1.450	0.051	0.057
G	2.900	3.300	0.114	0.130
H	15.000	16.000	0.591	0.630
I	0.380	0.420	0.015	0.017
J	4.450	4.550	0.175	0.179
K	1.250	1.350	0.049	0.053
L	6.350	6.550	0.250	0.258
M	5.080 Typ		0.200 Typ	
N	2.540 Typ		0.100 Typ	
O	0.760	0.840	0.030	0.033
P	3.100	3.300	0.122	0.130